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SI2328DS

100V 3.5A N-Channel MOSFET

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General Features

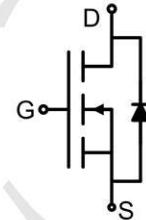
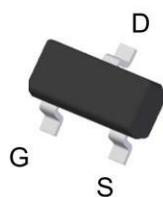
- $V_{DS} = 100V, I_D = 3.5A$
- $R_{DS(ON)} < 130m\Omega @ V_{GS}=10V$ (96m Ω Typ)
- $R_{DS(ON)} < 180m\Omega @ V_{GS}=4.5V$ (140m Ω Typ)

Application

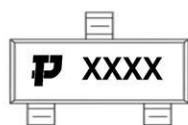
- Load/Power Switching
- Interfacing Switching
- Battery Management for Ultra Small Portable
- Logic Level Shift

Package and Pin Configuration

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Marking:



“P” is TECHPUBLIC LOGO
“XXXX” Marking ID (Please see the last page for details)

Absolute Maximum Ratings ($T_A=25^\circ C$ unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V_{DS}	100	V
Gate-Source Voltage	V_{GS}	± 20	V
Drain Current-Continuous	I_D	3.5	A
Drain Current-Pulsed (Note 1)	I_{DM}	20	A
Maximum Power Dissipation	P_D	1.5	W
Operating Junction and Storage Temperature Range	T_J, T_{STG}	-55 To 175	°C

Thermal Characteristic

Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{\theta JA}$	100	°C/W
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Electrical Characteristics ($T_A=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV_{DSS}	$\text{V}_{\text{GS}}=0\text{V}, \text{I}_D=250\mu\text{A}$	100	-	-	V
Zero Gate Voltage Drain Current	I_{DSS}	$\text{V}_{\text{DS}}=100\text{V}, \text{V}_{\text{GS}}=0\text{V}$	-	-	1	μA
Gate-Body Leakage Current	I_{GSS}	$\text{V}_{\text{GS}}=\pm20\text{V}, \text{V}_{\text{DS}}=0\text{V}$	-	-	±100	nA
On Characteristics <small>(Note 3)</small>						
Gate Threshold Voltage	$\text{V}_{\text{GS(th)}}$	$\text{V}_{\text{DS}}=\text{V}_{\text{GS}}, \text{I}_D=250\mu\text{A}$	1.0	1.5	2.0	V
Drain-Source On-State Resistance	$\text{R}_{\text{DS(ON)}}$	$\text{V}_{\text{GS}}=10\text{V}, \text{I}_D=3\text{A}$	-	96	130	$\text{m}\Omega$
		$\text{V}_{\text{GS}}=4.5\text{V}, \text{I}_D=1\text{A}$	-	140	180	
Forward Transconductance	g_{FS}	$\text{V}_{\text{DS}}=5\text{V}, \text{I}_D=3\text{A}$	-	5	-	S
Dynamic Characteristics <small>(Note 4)</small>						
Input Capacitance	C_{iss}	$\text{V}_{\text{DS}}=50\text{V}, \text{V}_{\text{GS}}=0\text{V},$ $F=1.0\text{MHz}$	-	650	-	PF
Output Capacitance	C_{oss}		-	24	-	PF
Reverse Transfer Capacitance	C_{rss}		-	20	-	PF
Switching Characteristics <small>(Note 4)</small>						
Turn-on Delay Time	$t_{\text{d(on)}}$	$\text{V}_{\text{DD}}=50\text{V}, \text{R}_L=19\Omega$ $\text{V}_{\text{GS}}=10\text{V}, \text{R}_G=3\Omega$	-	6	-	nS
Turn-on Rise Time	t_r		-	4	-	nS
Turn-Off Delay Time	$t_{\text{d(off)}}$		-	20	-	nS
Turn-Off Fall Time	t_f		-	4	-	nS
Total Gate Charge	Q_g	$\text{V}_{\text{DS}}=50\text{V}, \text{I}_D=3\text{A},$ $\text{V}_{\text{GS}}=10\text{V}$	-	20	-	nC
Gate-Source Charge	Q_{gs}		-	2.1	-	nC
Gate-Drain Charge	Q_{gd}		-	3.3	-	nC
Drain-Source Diode Characteristics						
Diode Forward Voltage <small>(Note 3)</small>	V_{SD}	$\text{V}_{\text{GS}}=0\text{V}, \text{I}_S=3\text{A}$	-	-	1.2	V
Diode Forward Current <small>(Note 2)</small>	I_S			3.5		A



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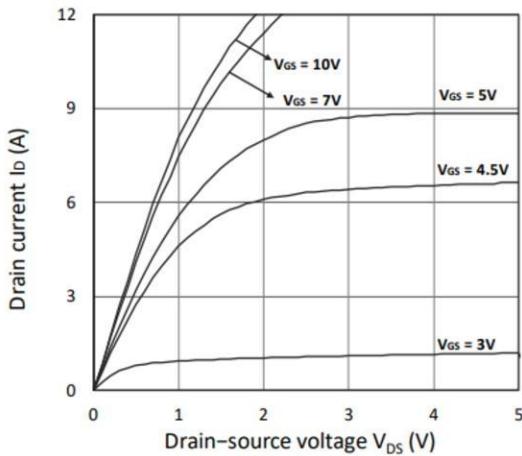


Figure 1. Output Characteristics

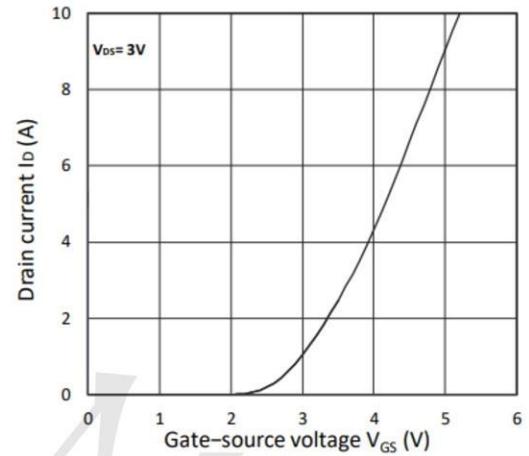


Figure 2. Transfer Characteristics

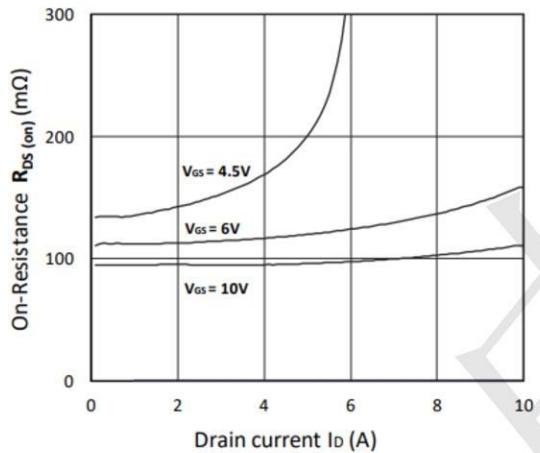


Figure 3. R_{D(on)} VS.I_D

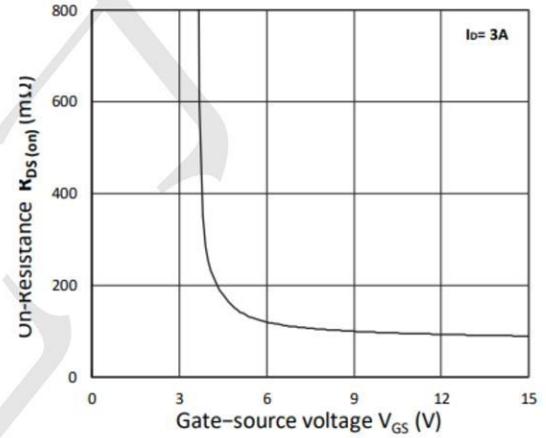


Figure 4. R_{D(on)} VS.V_G

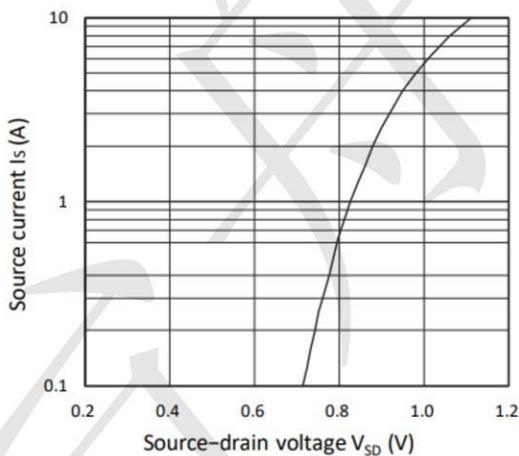


Figure 5. I_S VS.V_{SD}

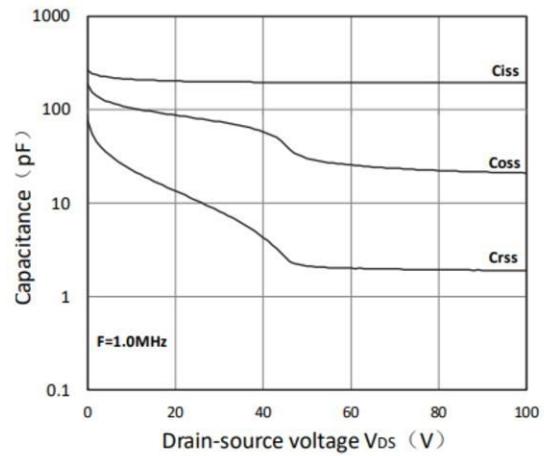


Figure 6. Capacitance Characteristics



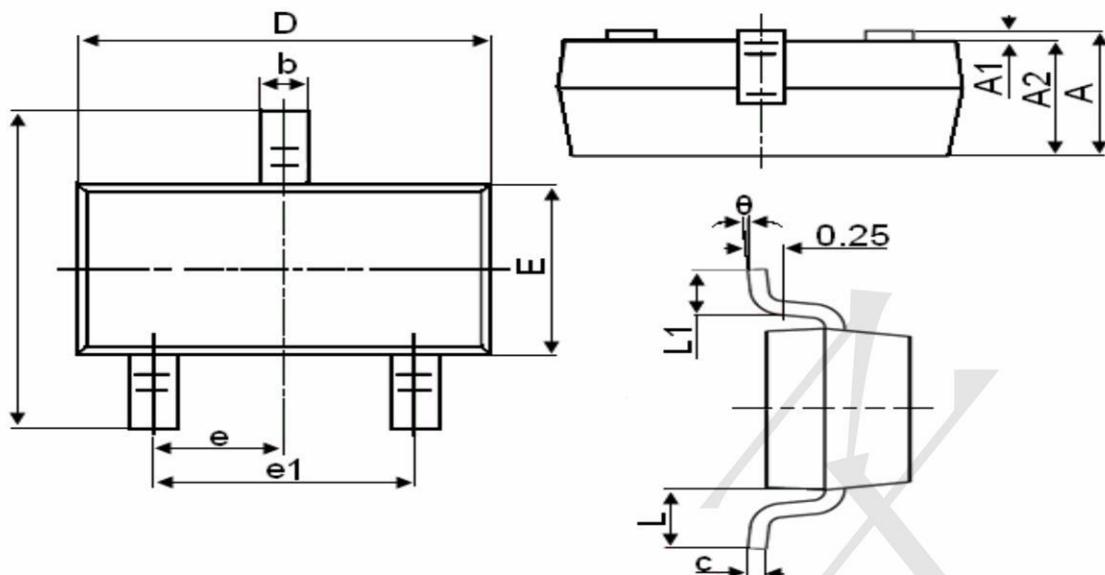
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Package Outline Dimensions (SOT-23)



Symbol	Dimensions in Millimeters	
	MIN.	MAX.
A	0.900	1.150
A1	0.000	0.100
A2	0.900	1.050
b	0.300	0.500
c	0.080	0.150
D	2.800	3.000
E	1.200	1.400
E1	2.250	2.550
e	0.950TYP	
e1	1.800	2.000
L	0.550REF	
L1	0.300	0.500
θ	0°	8°

Marking:



“P” is TECHPUBLIC LOGO
“3N” is Part number,fixed
“xx”is internal code

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